

FDS86240

Data Sheet

Trans MOSFET N-CH 150V 7.5A 8Pin SOIC N T/R

Manufacturers	ON Semiconductor, LLC	
Package/Case	SO-8	899
Product Type	Transistors	Leve -
RoHS	Green	
Lifecycle		Images are for reference only
Please submit RFQ for FDS86240 or Email to us: sales@ovaga.com We will contact you in 12 hours.		

General Description

This N-Channel MOSFET is produced using an advanced Power Trench® process that has been optimized for rDS(on), switching performance and ruggedness.

Features

Max = 10 V,>

Max = 6 V,>

High Performance Trench Technology for Extremely Low rDS(on)

High Power and Current Handling Capability in a Widely Used Surface Mount Package

Related Products

erovada .

<u>FDC645N</u>

ON Semiconductor, LLC SSOT-6



FDC637BNZ

ON Semiconductor, LLC SSOT-6

Application

ONSEMI



FDC6305N

ON Semiconductor, LLC SSOT-6



FDC602P ON Semiconductor, LLC SOT163



FDD8647L

ON Semiconductor, LLC TO-252-3



FDD5N50NZTM

ON Semiconductor, LLC TO-252



FDB070AN06A0

ON Semiconductor, LLC TO-263

FDD3670

ON Semiconductor, LLC TO-252AA